









	<h2 style="color: #E67E22;">SUD50N03-11-E3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SUD50N03-11-E3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET N-CH 30V 50A TO252
	Datenblätter:  SUD50N03-11-E3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 3623 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SUD50N03-11-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 50A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	3623 pcs Stock
detaillierte Beschreibung	N-Channel 30V 50A (Tc) 7.5W (Ta), 62.5W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	7.5W (Ta), 62.5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	50A (Tc)
Rds On (Max) @ Id, Vgs	11 mOhm @ 25A, 10V
VGS (th) (Max) @ Id	800mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	20nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1130pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

SUD50N03-11-E3 ist neu im Original, Suche SUD50N03-11-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N03-11-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD50N03-11-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD50N03-12P-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V TO252</p>	 <p>SUD50N03-11 VISHAY SUD50N03-11 VISHAY</p>	 <p>SUD50N03-10CP V SUD50N03-10CP V</p>	 <p>SUD50N03-10P SILICON SUD50N03-10P SILICON</p>
 <p>SUD50N03-12P VISHAY SUD50N03-12P VISHAY</p>	 <p>SUD50N03-11-E3 Vishay / Siliconix MOSFET N-CH 30V 50A TO252</p>	 <p>SUD50N03-11-T4-E3 VIS VIS TO-252</p>	 <p>SUD50N03-11-E3-PBF VISHAY VISHAY TO252</p>

heiße Teile

Mehr

⊛ SUD50N025-06P-E3	↔ SUD50N025-09	⇒ SUD50N025-09BP-4E3	D SUD50N025-09BP-E3	⇒ SUD50N03
⊣ SUD50N03-06	⊛ SUD50N03-06P	D SUD50N03-06P-E3	⇒ SUD50N03-06P-E3	⇒ SUD50N03-07
⊛ SUD50N03-07AP	⊣ SUD50N03-07P	⊛ SUD50N03-09	↔ SUD50N03-09P	⇒ SUD50N03-09P-E3
D SUD50N03-09P-E3	⊛ SUD50N03-10	⊣ SUD50N03-10-T4	⊛ SUD50N03-10AP	⇒ SUD50N03-10BP
⇒ SUD50N03-10BP-T4	↔ SUD50N03-10CP	⊛ SUD50N03-10P	⊣ SUD50N03-11	⇒ SUD50N03-11-E3
↔ SUD50N03-12P	⇒ SUD50N03-12P-E3	D SUD50N03-12P-E3	⊛ SUD50N03-16P	⊣ SUD50N03-7M3P
⊛ SUD50N03A	D SUD50N04-05L	⇒ SUD50N04-05L-E3	↔ SUD50N04-05L-E3	⇒ SUD50N04-06H
⊣ SUD50N04-06P	⊛ SUD50N04-07	↔ SUD50N04-07-T4-GE3	⇒ SUD50N04-07L	⇒ SUD50N04-07L-E3
⊛ SUD50N04-09H	⊣ SUD50N04-09H-E3	⊛ SUD50N04-09H-E3	D SUD50N04-09L-E3	⇒ SUD50N04-10P-E3
↔ SUD50N04-13P	⊛ SUD50N04-13P-E3	⊣ SUD50N04-16P	⊛ SUD50N04-25P	⇒ SUD50N04-37P

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